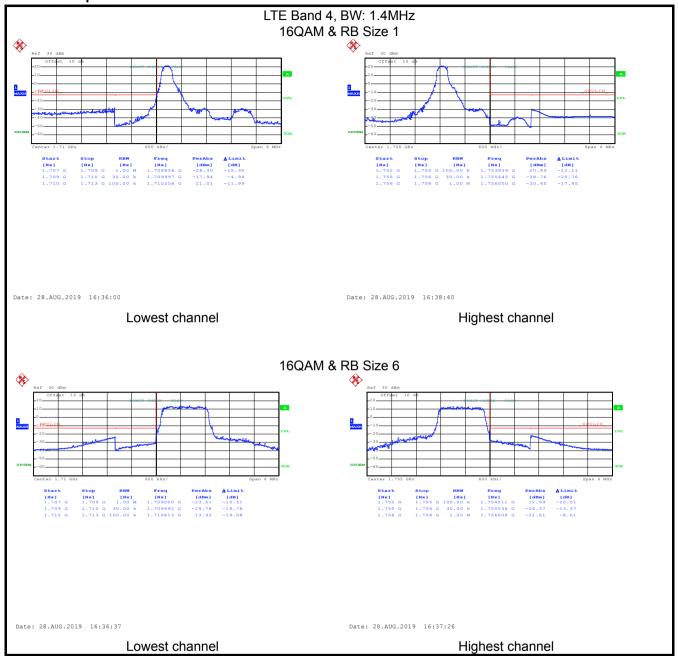


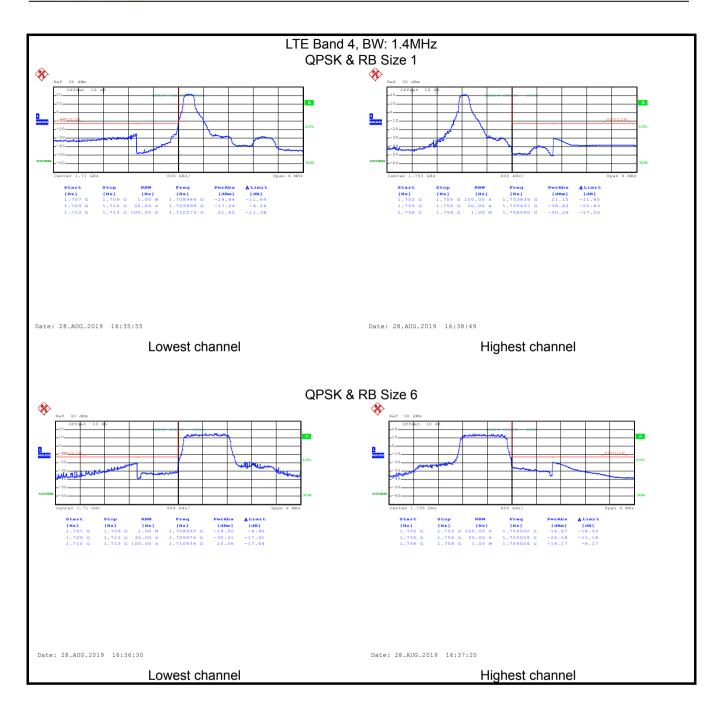


Band edge emission:

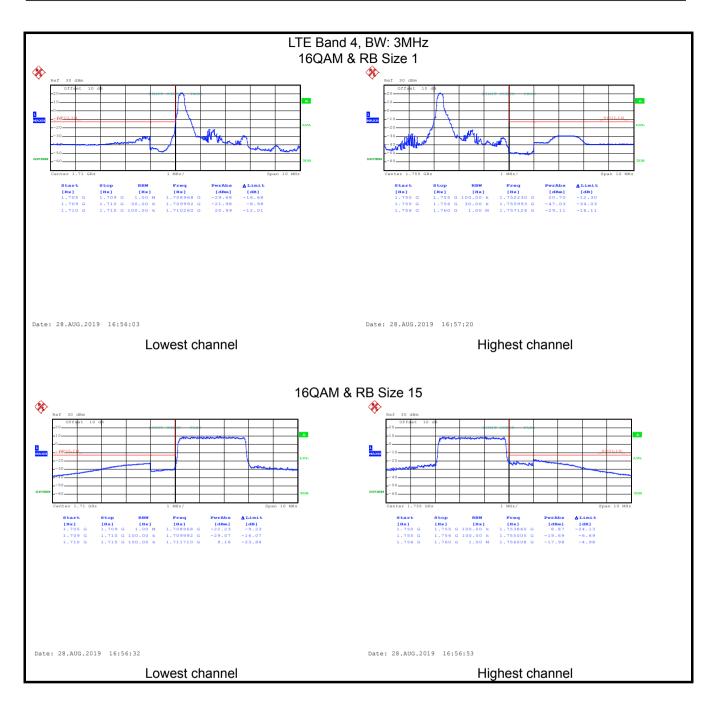
LTE Band 4 part:



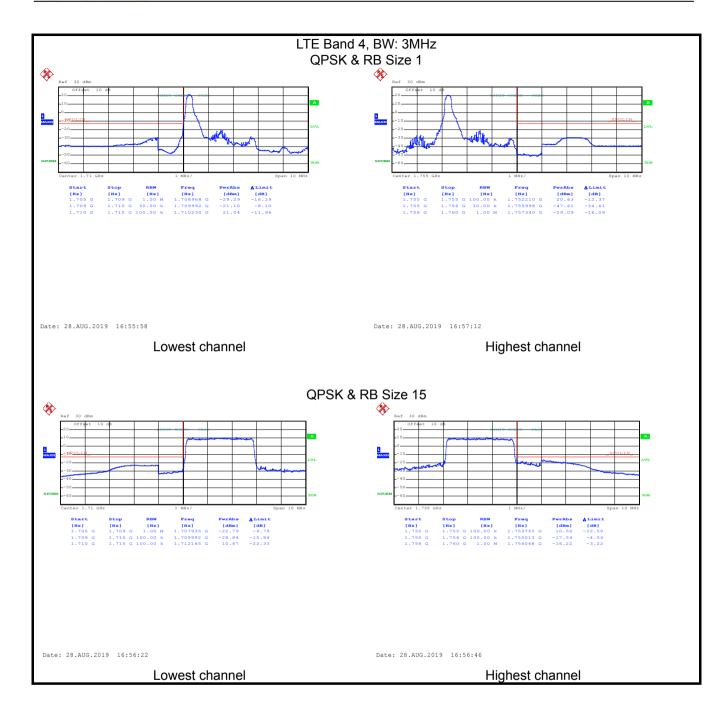




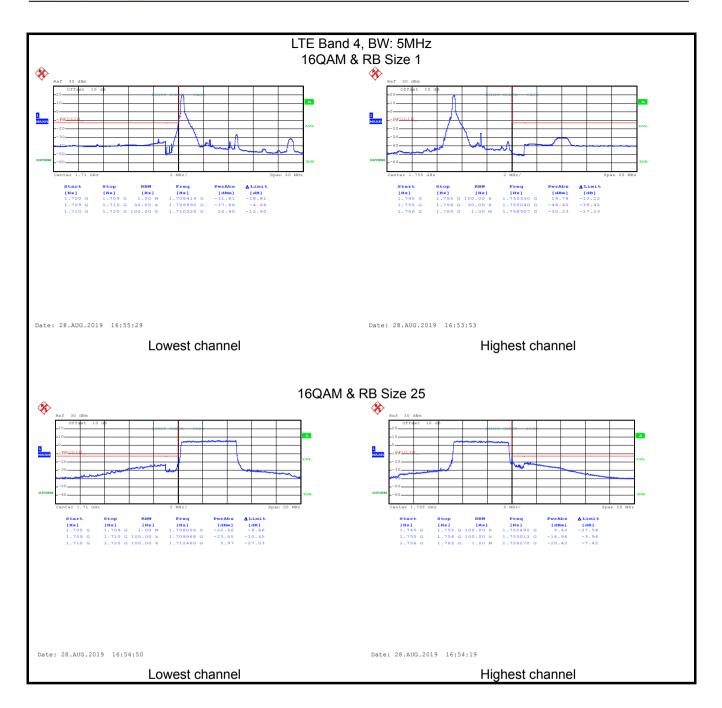




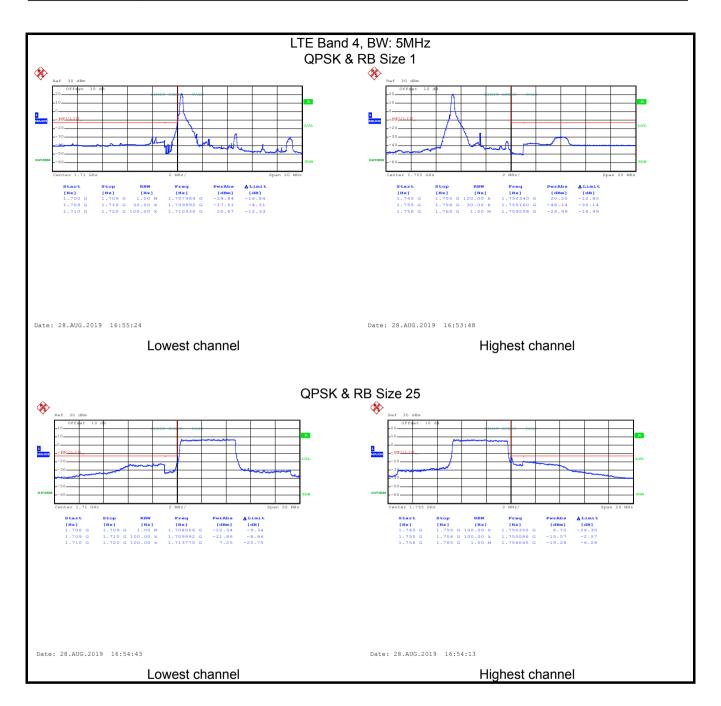




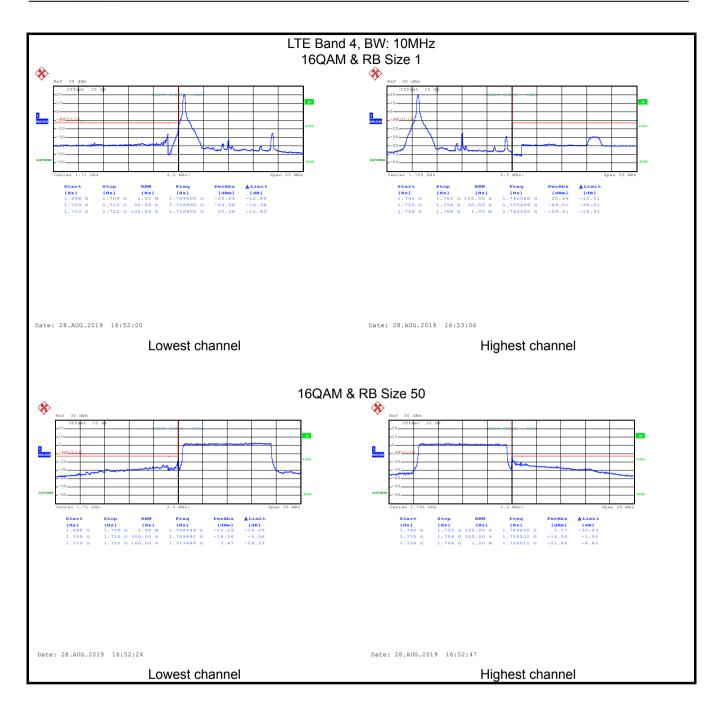




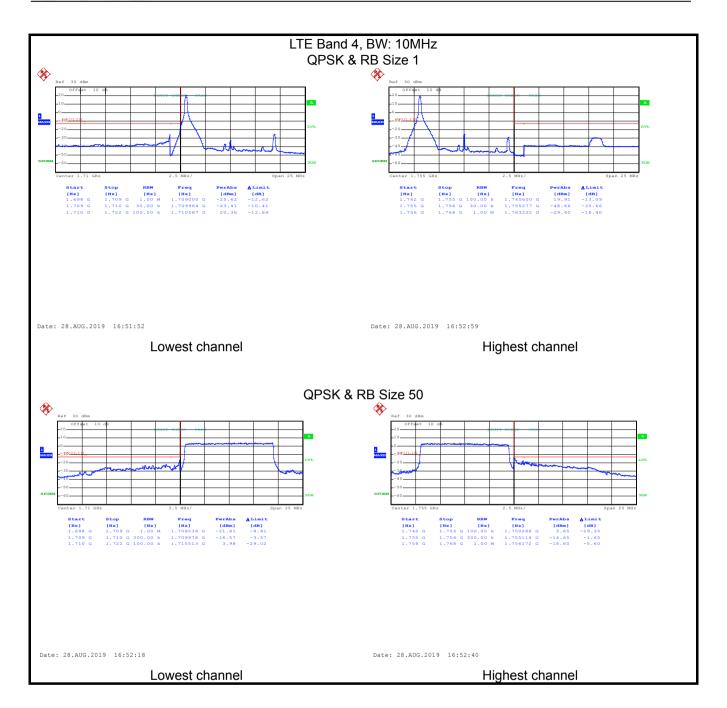




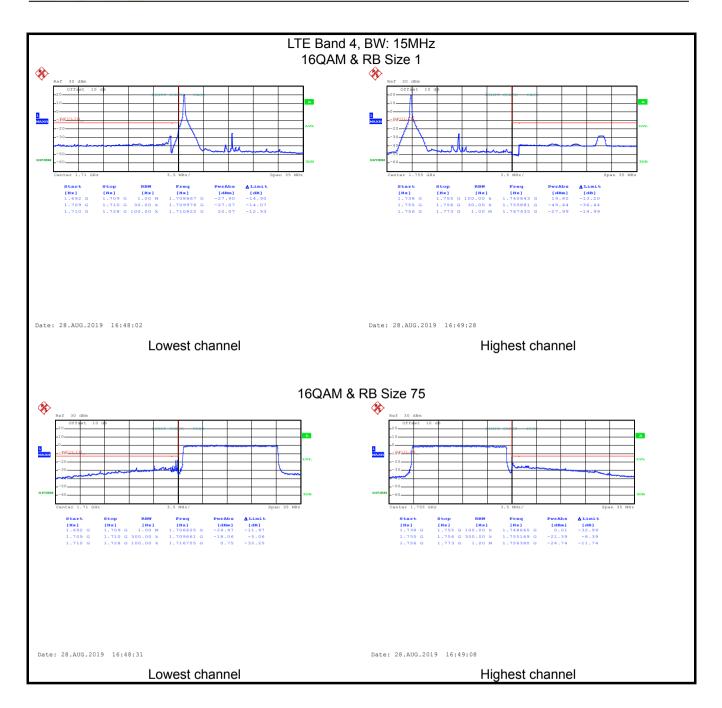




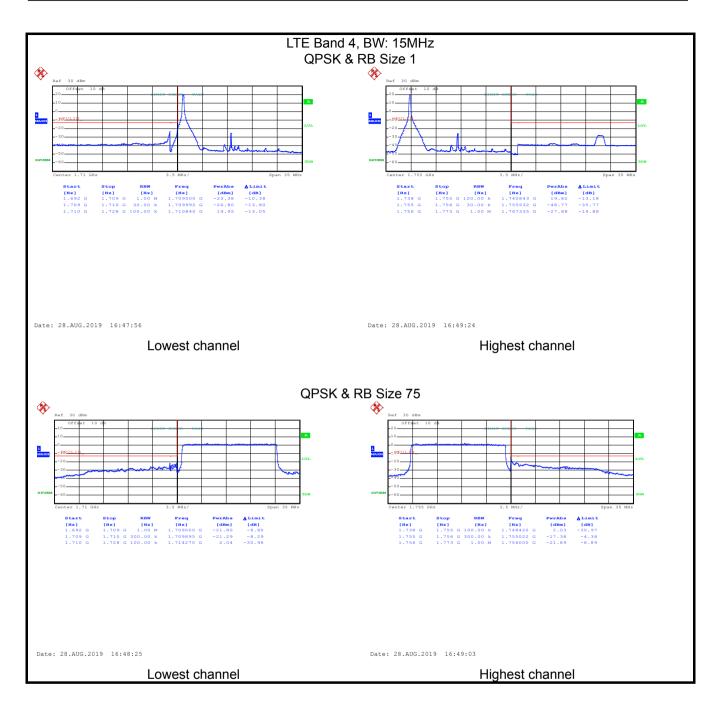




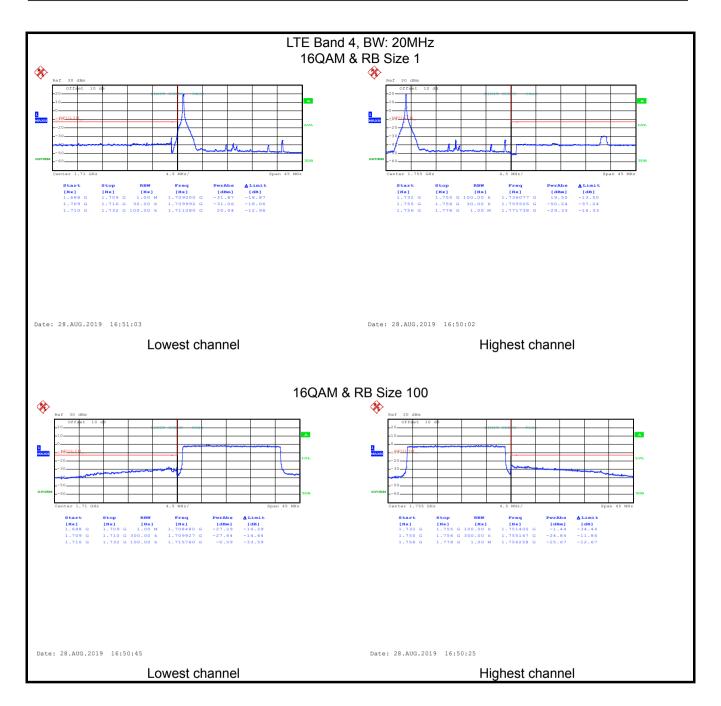




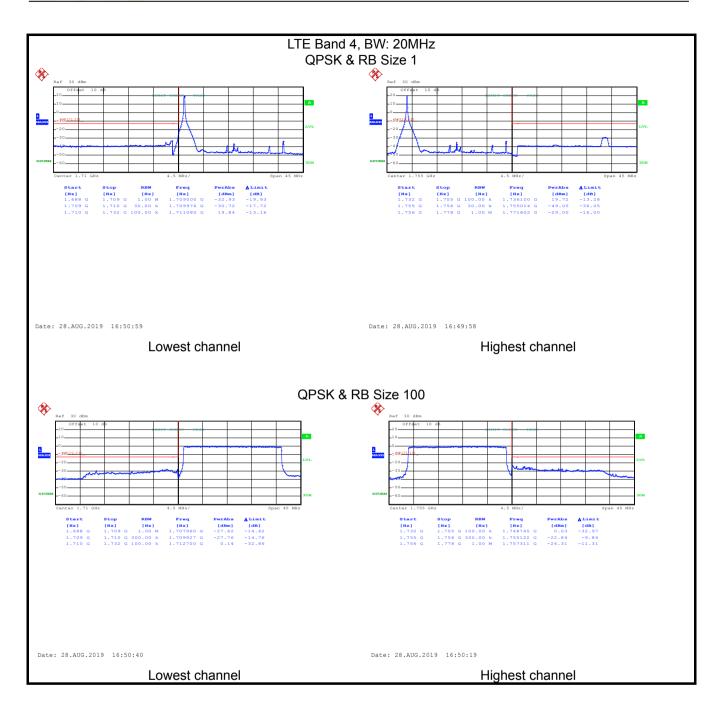






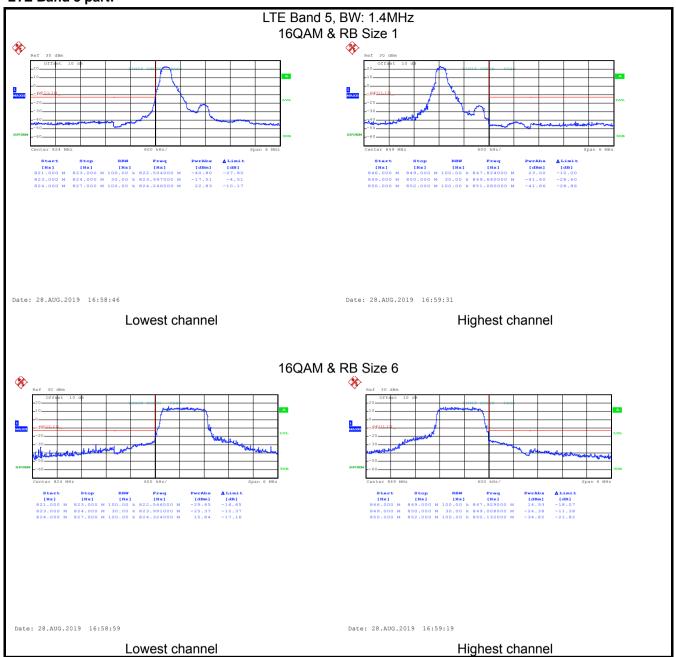




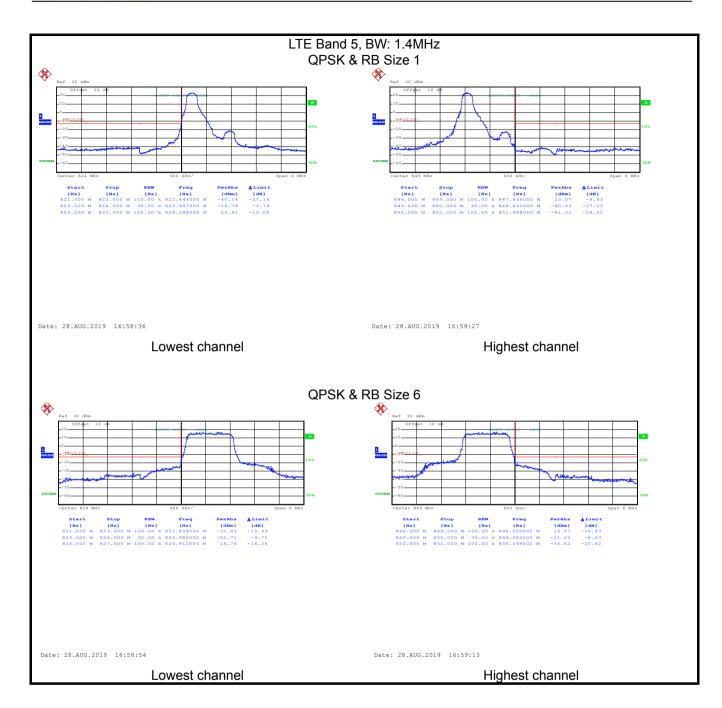




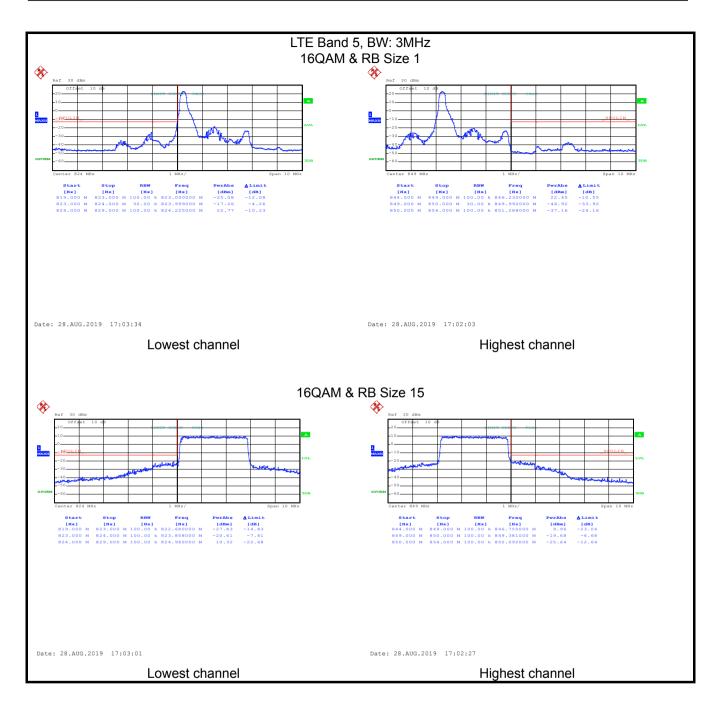
LTE Band 5 part:



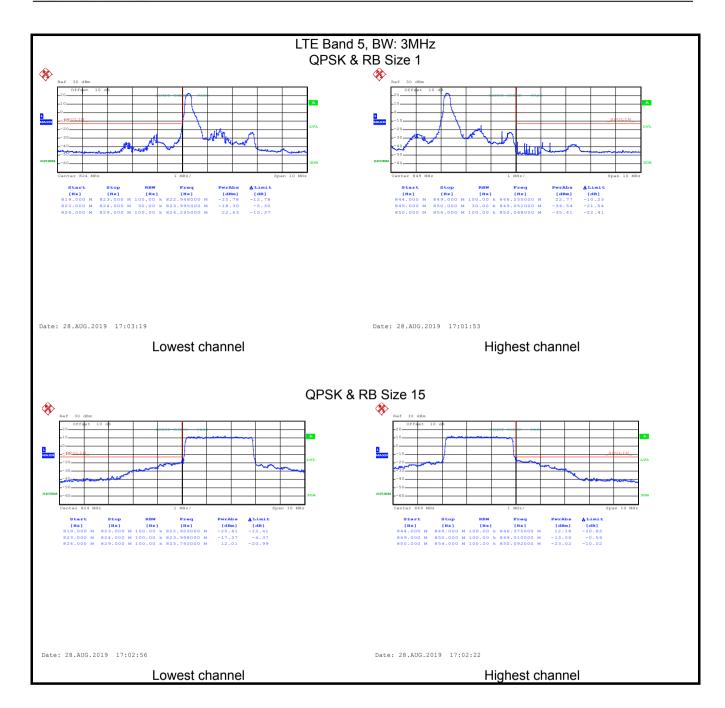




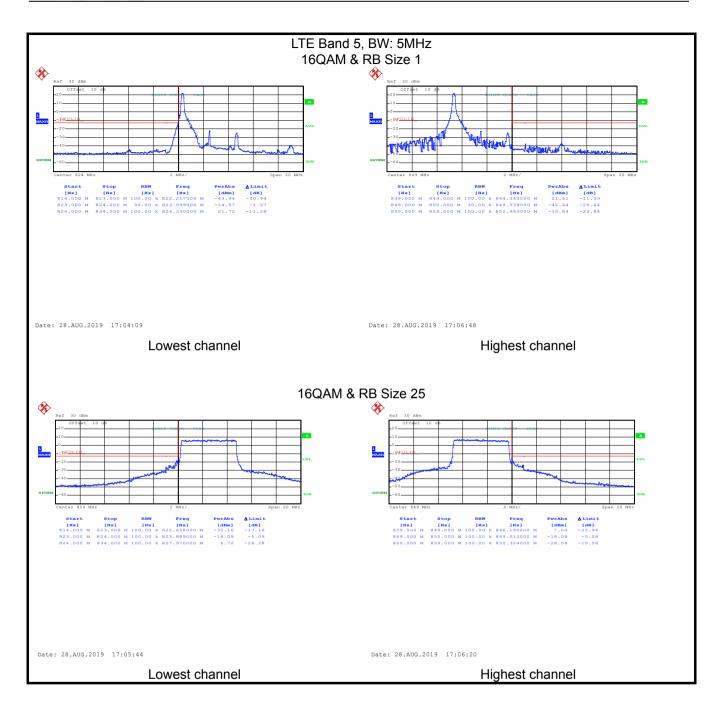




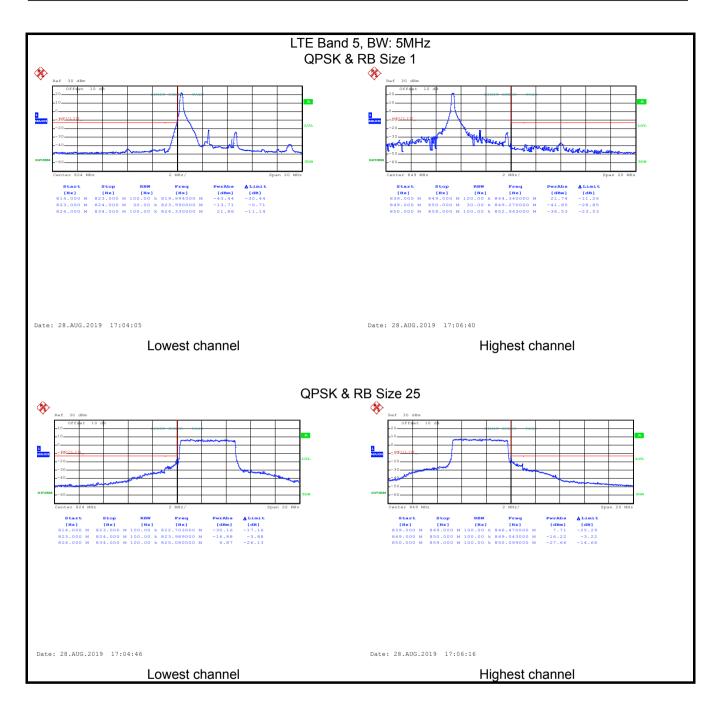




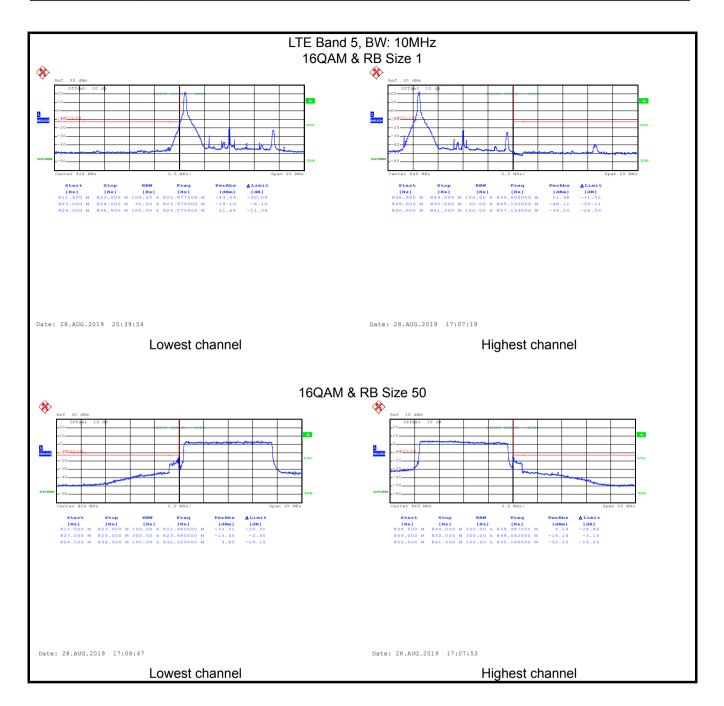




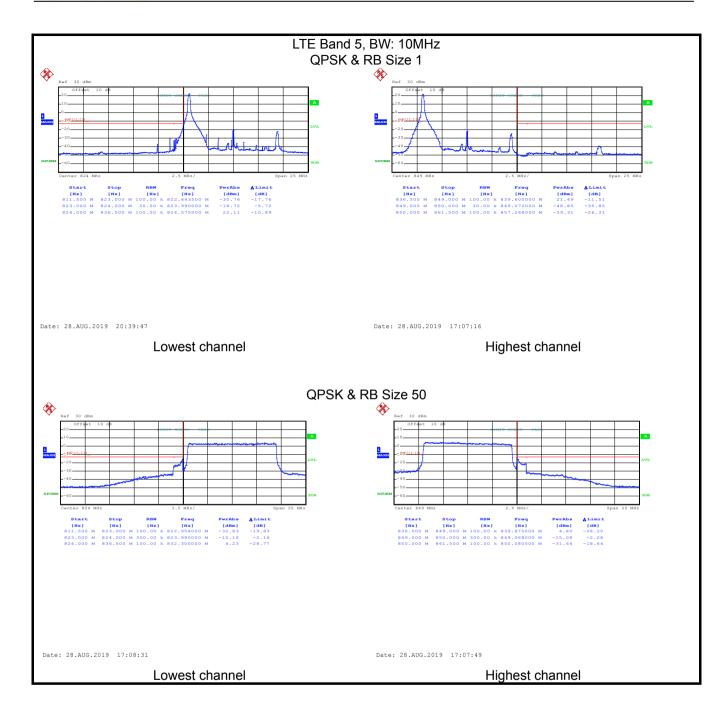






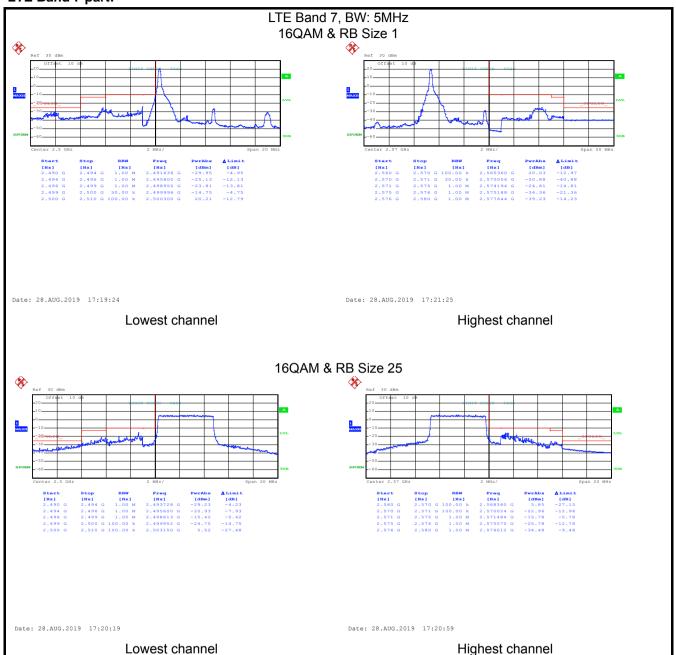




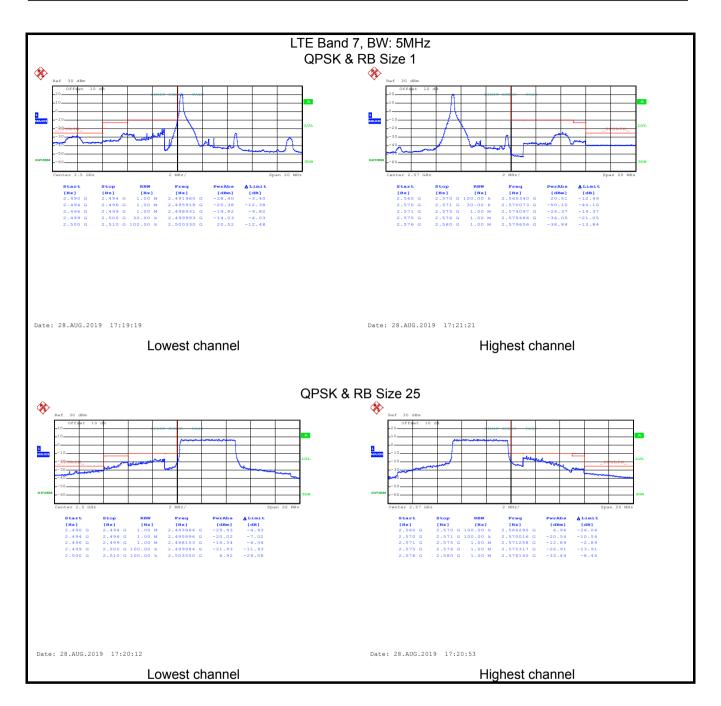




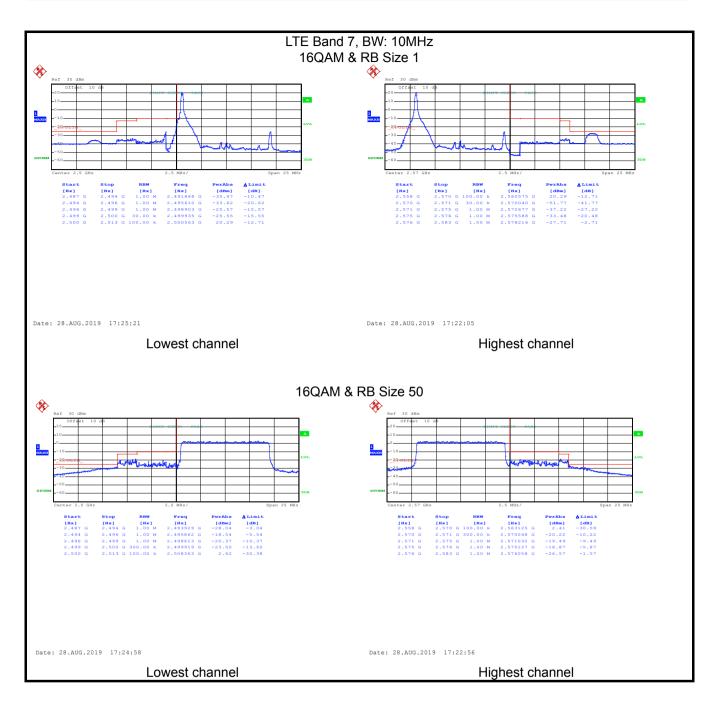
LTE Band 7 part:



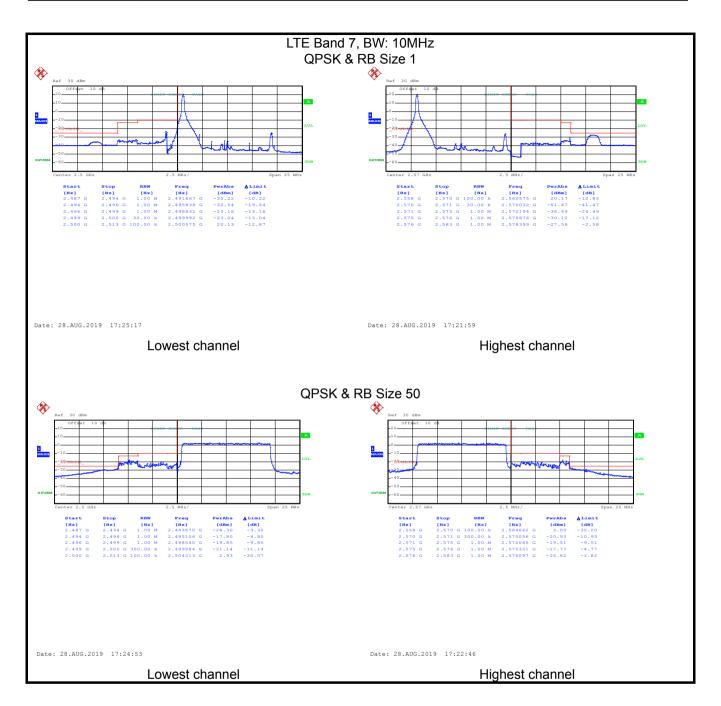




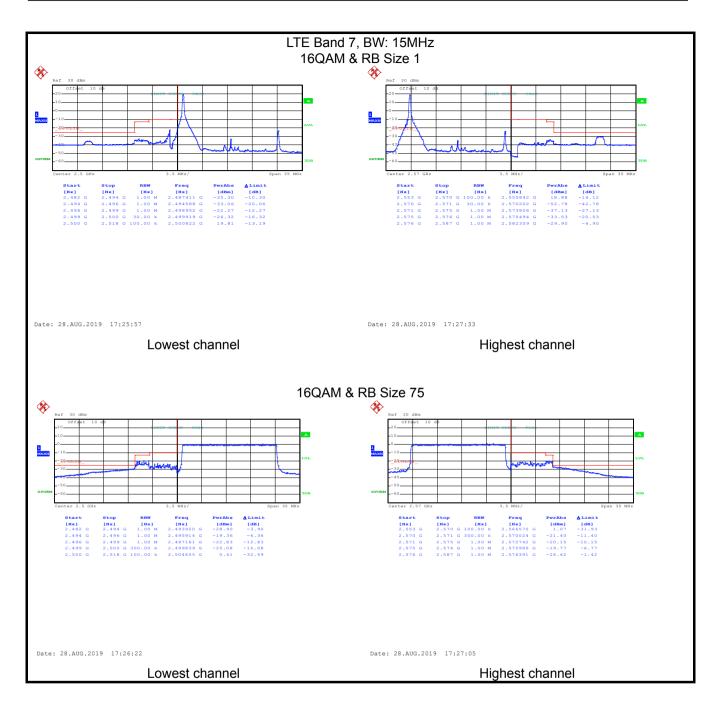




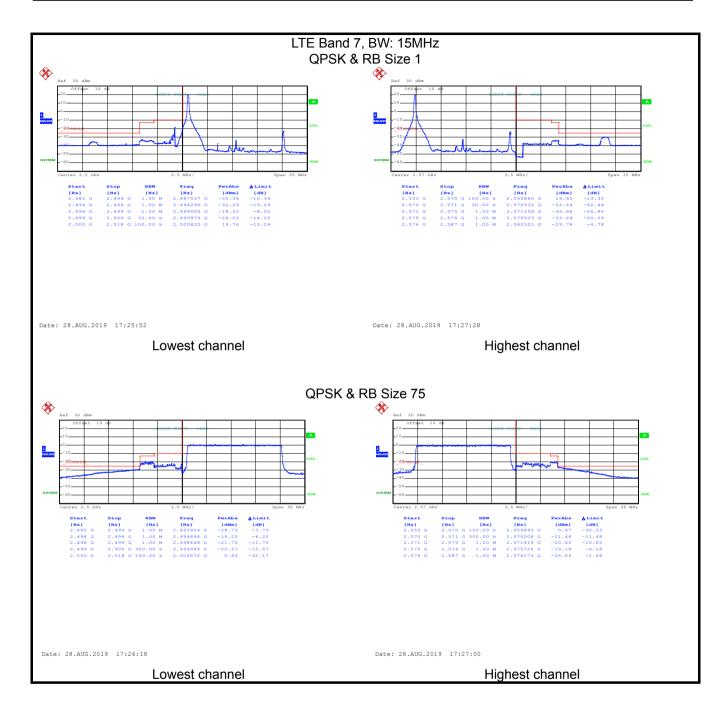




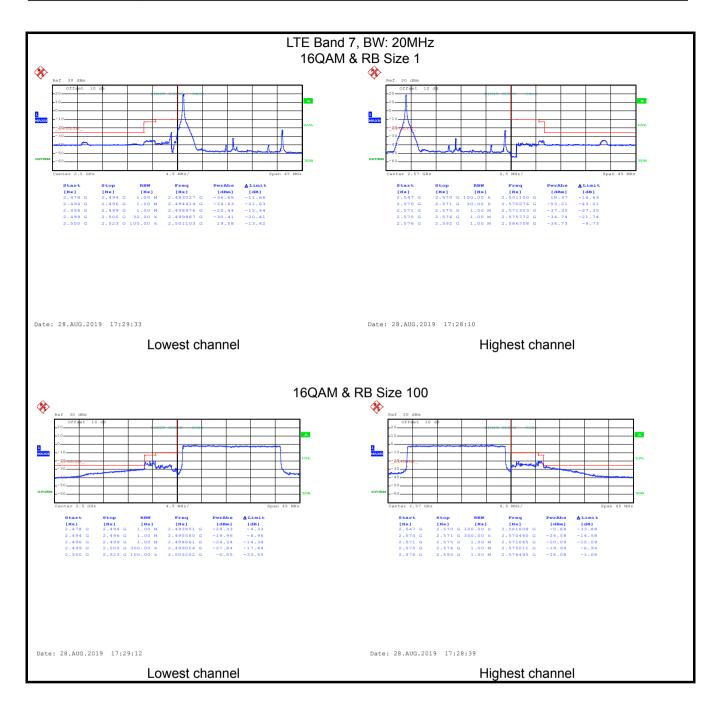




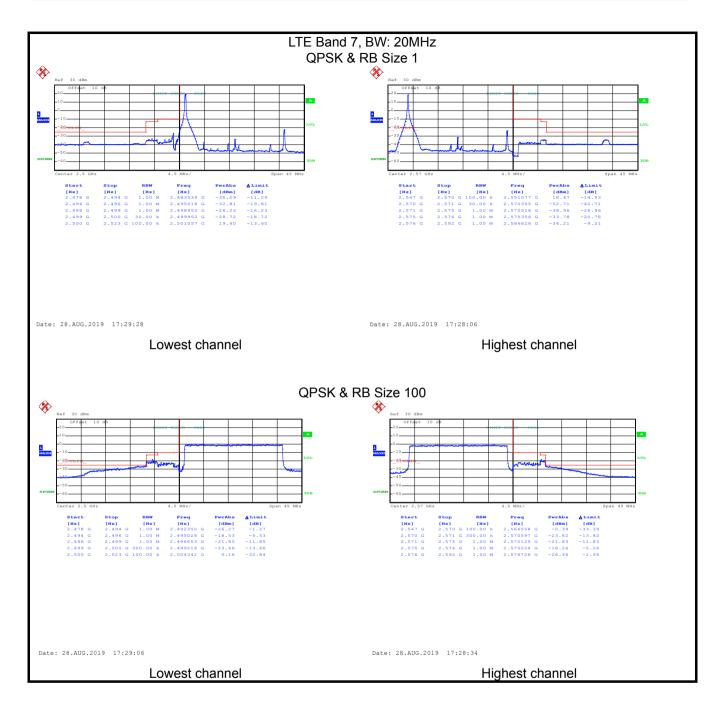














6.5 Field strength of spurious radiation measurement

0.5 Field strength of sp	urious radiation measurement
Test Requirement:	Part 22.917(b), Part 27.53(m), Part 27.53(h)
Test Method:	ANSI/TIA-603-D 2010
Limit:	LTE Band 4 & 5: The power of any emission outside a licensee's frequency block shall be attenuated below the transmitter power (P) in watts by at least 43 + 10 log ₁₀ (P) dB (-13 dBm). LTE Band 7:
	For mobile digital stations, the attenuation factor shall be not less than 40 + 10 log (P) dB on all frequencies between the channel edge and 5 megahertz from the channel edge, 43 + 10 log (P) dB on all frequencies between 5 megahertz and X megahertz from the channel edge, and 55 + 10 log (P) dB on all frequencies more than X megahertz from the channel edge, where X is the greater of 6 megahertz or the actual emission bandwidth as defined in paragraph (m)(6) of this section. In addition, the attenuation factor shall not be less that 43 + 10 log (P) dB on all frequencies between 2490.5 MHz and 2496 MHz and 55 + 10 log (P) dB at or below 2490.5 MHz.
Test setup:	Below 1GHz
	Antenna Tower Ground Reference Plane Ground Reference Plane Generator Amplifier Above 1GHz
	Antenna Tower Ground Reference Plane Test Receiver Antenna Tower Controller Angler Controller
Test Procedure:	The EUT was placed on an non-conductive turntable using a non-conductive support. The radiated emission at the fundamental frequency was measured at 3 m with a test antenna and EMI spectrum analyzer.
	 During the tests, the antenna height and the EUT azimuth were varied in order to identify the maximum level of emissions from the EUT. This maximization process was repeated with the EUT positioned in each of its three orthogonal orientations. The frequency range up to tenth harmonic was investigated for each
	of three fundamental frequency (low, middle and high channels).



	Once spurious emission was identified, the power of the emission was determined using the substitution method. 4. The spurious emissions attenuation was calculated as the difference between radiated power at the fundamental frequency and the spurious emissions frequency. ERP / EIRP = S.G. output (dBm) + Antenna Gain(dB/dBi) - Cable Loss (dB)
To at In atm. magnets.	Defeate costion F.O for details
Test Instruments:	Refer to section 5.9 for details
Test mode:	Refer to section 5.3 for details.
Test results:	Passed

Measurement Data:

LTE Band 4 part:

	LT	E Band 4, WB: 1.4MH	lz			
	RI	B size 1 & RB offset ()			
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result		
Frequency (Wiriz)	Polarization	Level (dBm)	Limit (ubin)	Result		
		Lowest Channel				
3421.40	Vertical	-50.43				
5132.10	V	-40.88				
6842.80	V	-39.57	-13.00	Pass		
3421.40	Horizontal	-49.82	-13.00	F d 5 5		
5132.10	Н	-37.24				
6842.80	Н	-39.11				
		Middle Channel				
3465.00	Vertical	-50.91				
5197.50	V	-40.23				
6930.00	V	-39.51	42.00	Desc		
3465.00	Horizontal	-49.74	-13.00	Pass		
5197.50	Н	-37.85				
6930.00	Н	-39.96				
		Highest Channel				
3508.60	Vertical	-50.91				
5262.90	V	-40.92				
7017.20	V	-39.58	42.00	Desc		
3508.60	Horizontal	-49.37	-13.00 Pass			
5262.90	Н	-37.15				
7017.20	Н	-39.55				

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



	LT	E Band 4, WB: 20MH	z	
	R	B size 1 & RB offset ()	
Frequency (MHz)	Spurious	Spurious Emission		Result
Frequency (IVII 12)	Polarization	Level (dBm)	Limit (dBm)	Kesuit
		Lowest Channel		
3440.00	Vertical	-50.47		
5160.00	V	-40.16		
6880.00	V	-39.51	-13.00	Pass
3440.00	Horizontal	-49.30	-13.00	Pass
5160.00	Н	-37.16		
6880.00	Н	-39.54		
		Middle Channel		
3465.00	Vertical	-50.19		
5197.50	V	-40.97		
6930.00	V	-39.41	-13.00	Door
3465.00	Horizontal	-49.26	-13.00	Pass
5197.50	Н	-37.61		
6930.00	Н	-39.47		
		Highest Channel		
3490.00	Vertical	-50.16		
5235.00	V	-40.73		
6980.00	V	-39.64	-13.00	Pass
3490.00	Horizontal	-49.28	-13.00	Pass
5235.00	Н	-37.61		
6980.00	Н	-39.11		

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





LTE Band 5 part:

	LT	E Band 5, WB: 1.4MH	Iz	
	RI	B size 1 & RB offset ()	
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result
Frequency (Miriz)	Polarization	Level (dBm)	Lilliit (ubili)	Kesuit
		Lowest Channel		
1649.40	Vertical	-56.73		
2474.10	V	-54.92		
3298.80	V	-51.23	-13.00	Pass
1649.40	Horizontal	-55.92	-13.00	P 455
2474.10	Н	-53.41		
3298.80	Н	-51.74		
		Middle Channel		
1673.00	Vertical	-56.85		
2509.50	V	-54.19		
3346.00	V	-51.73	-13.00	Pass
1673.00	Horizontal	-55.16	-13.00	P 455
2509.50	Н	-53.85		
3346.00	Н	-51.26		
		Highest Channel		
1696.60	Vertical	-56.61		
2544.90	V	-54.23		
3393.20	V	-51.85	12.00	Door
1696.60	Horizontal	-55.70	-13.00	Pass
2544.90	Н	-53.16		
3393.20	Н	-51.84		

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



	LT	E Band 5, WB: 10MF	łz		
	R	B size 1 & RB offset	0		
Frequency (MHz)	Spurious Emission		Limit (dRm)	Result	
Frequency (MHZ)	Polarization	Level (dBm)	Limit (dBm)	Result	
		Lowest Channel			
1658.00	Vertical	-56.91			
2487.00	V	-54.16			
3316.00	V	-51.85	-13.00	Pass	
1658.00	Horizontal	-55.73	-13.00	Fd55	
2487.00	Н	-53.16			
3316.00	Н	-51.88			
		Middle Channel			
1673.00	Vertical	-56.16			
2509.50	V	-54.99			
3346.00	V	-51.34	-13.00	Pass	
1673.00	Horizontal	-55.29	-13.00	Fd55	
2509.50	Н	-53.16			
3346.00	Н	-51.75			
		Highest Channel			
1688.00	Vertical	-56.22			
2532.00	V	-54.19			
3376.00	V	-51.73	-13.00	Pass	
1688.00	Horizontal	-55.85	-13.00	Pass	
2532.00	Н	-53.94			
3376.00	Н	-51.37			

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





LTE Band 7 part:

	L	TE Band 7, WB: 5MH	Z	
	R	B size 1 & RB offset (0	
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result
Frequency (IVII 12)	Polarization	Level (dBm)	Limit (dbin)	Kesuit
		Lowest Channel		
5005.00	Vertical	-47.37		
7507.50	V	-39.51		
10010.00	V	-36.52	-25.00	Pass
5005.00	Horizontal	-47.52	-25.00	F 455
7507.50	Н	-39.57		
10010.00	Н	-36.23		
		Middle Channel		
5070.00	Vertical	-47.15		
7605.00	V	-39.71		
10140.00	V	-36.55	-25.00	Pass
5070.00	Horizontal	-47.13	-25.00	Pa55
7605.00	Н	-39.85		
10140.00	Н	-36.71		
		Highest Channel		
5135.00	Vertical	-47.53		
7702.50	V	-39.54		
10270.00	V	-36.26	25.00	Door
5135.00	Horizontal	-47.52	-25.00	Pass
7702.50	Н	-39.16		
10270.00	Н	-36.54		

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



	Lī	TE Band 7, WB: 20MH	İz			
	R	B size 1 & RB offset (0			
Eroguenov (MHz)	Spurious Emission		Limit (dPm)	Decelle		
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result		
		Lowest Channel				
5020.00	Vertical	-47.94				
7530.00	V	-39.15				
10040.00	V	-36.84	-25.00	Pass		
5020.00	Horizontal	-47.55	-25.00	F455		
7530.00	Н	-39.43				
10040.00	Н	-36.18				
		Middle Channel				
5070.00	Vertical	-47.85				
7605.00	V	-39.82				
10140.00	V	-36.40	-25.00	Pass		
5070.00	Horizontal	-47.53	-25.00	F d 5 5		
7605.00	Н	-39.85				
10140.00	Н	-36.81				
		Highest Channel				
5120.00	Vertical	-47.51				
7680.00	V	-39.50				
10240.00	V	-36.81	25.00	Page		
5120.00	Horizontal	-47.44				
7680.00	Н	-39.16				
10240.00	Н	-36.18				

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



6.6 Frequency stability V.S. Temperature measurement

Test Requirement:	Part 22.355, Part 27.54, Part 2.1055(a)(1)(b)
Test Method:	ANSI/TIA-603-D 2010
Limit:	±2.5ppm for band 5 within authorized band for band 4 and 7
Test procedure:	SS Divider Temperature & Humidity Chamber Power Source The equipment under text was connected to an external DC newer.
Test procedure:	 The equipment under test was connected to an external DC power supply and input rated voltage. RF output was connected to a frequency counter or spectrum analyzer via feed through attenuators. The EUT was placed inside the temperature chamber. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and measure EUT 25°C operating frequency as reference frequency. Turn EUT off and set the chamber temperature to -30°C. After the temperature stabilized for approximately 30 minutes recorded the frequency. Repeat step measure with 10°C increased per stage until the highest temperature of +50°C reached
Test Instruments:	Refer to section 5.9 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed





Measurement Data (worst case):

LTE Band 4 part:

	requency: LTE Band 4	-		cnannel=1/32.5	UNIHZ
Power supplied (Vdc)	Temperature (°C) —	Hz	ency error	Limit (ppm)	Result
(v do)		QPSK	ppm		
	-30	196	0.113131	T	
	-20	184	0.106205		
	-10	173	0.099856		
	0	165	0.095238	within	
3.80	10	157	0.090620	authorized	Pass
0.00	20	146	0.084271	band	
	30	133	0.076768		
	40	125	0.072150		
	50	118	0.068110		
		16QAM			
	-30	163	0.094084		
	-20	154	0.088889]	
	-10	141	0.081385		
	0	134	0.077345	within	
3.80	10	126	0.072727	authorized	Pass
	20	112	0.064646	band	
	30	109	0.062915		
	40	117	0.067532		
	50	145	0.083694		





LTE Band 5 part:

Reference F	requency: LTE Band	5 (10MHz) Midd	dle channel=2052	5 channel=836.50	MHz
Power supplied	Temperature (°C)	Freque	ency error	Limit (ppm)	Result
(Vdc)	Temperature (c)	Hz	ppm	Limit (ppm)	rvesuit
		QPSK			
	-30	197	0.235505		
	-20	188	0.224746		
	-10	179	0.213987		
	0	170	0.203228		
3.80	10	166	0.198446	±2.5	Pass
	20	159	0.190078		
	30	148	0.176928	_	
	40	139	0.166169		
	50	120	0.143455		
		16QAM			
	-30	167	0.199641		
	-20	158	0.188882		
	-10	149	0.178123		
	0	138	0.164973		
3.80	10	130	0.155409	±2.5	Pass
	20	126	0.150628		
	30	119	0.142259		
	40	110	0.131500		
	50	140	0.167364]	





LTE Band 7 part:

Reference Fre	quency: LTE Band 7	(10MHz) Middle	channel=21100	Frequency=2535.	00MHz
Power supplied	Temperature (°C)	Freque	ency error	Limit (ppm)	Result
(Vdc)	remperature (c)	Hz	ppm	Limit (ppin)	Mesuit
		QPSK			
	-30	194	0.076529		
	-20	185	0.072978		
	-10	177	0.069822		
	0	168	0.066272	within	
3.80	10	157	0.061933	authorized	Pass
	20	149	0.058777	band	
	30	137	0.054043		
	40	123	0.048521		
	50	116	0.045759		
		16QAM			
	-30	161	0.063511		
	-20	150	0.059172		
	-10	145	0.057199		
	0	134	0.052860	within	
3.80	10	123	0.048521	authorized	Pass
	20	112	0.044181	band	
	30	101	0.039842		
	40	129	0.050888		
	50	154	0.060750		



6.7 Frequency stability V.S. Voltage measurement

Test Requirement:	Part 22.355, Part 27.54, Part 2.1055(d)(2)
Test Method:	ANSI/TIA-603-D 2010
Limit:	±2.5ppm for band 5 within authorized band for 4 and 7
Test setup:	SS EUT Divider Temperature & Humidity Chamber Power Source
Test procedure:	 Set chamber temperature to 25°C. Use a variable DC power source to power the EUT and set the voltage to rated voltage. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and recorded the frequency. Reduce the input voltage to specify extreme voltage variation (+/-15%) and endpoint, record the maximum frequency change.
Test Instruments:	Refer to section 5.9 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed



Measurement Data (worst case):

LTE Band 4 part:

Reference Frequency: LTE Band 4(10MHz) Middle channel=20175 channel=1732.50MHz					
Temperature (°C)	Power supplied	Frequency error		Limit (nnm)	Result
	(Vdc)	Hz	ppm	Limit (ppm)	Resuit
		QPSK			
	4.35	96	0.055411	within authorized band	
25	3.80	80	0.046176		Pass
	3.50	74	0.042713		
		16QAM			
25	4.35	92	0.053102	within authorized band	Pass
	3.80	83	0.047908		
	3.50	71	0.040981		
Note: Only the worst cas	se shown in the report.				

LTE Band 5 part:

Reference F	requency: LTE Band	5(10MHz) Middle	e channel=2052	5 channel=836.5	DMHz
Temperature (°C)	Power supplied	Frequency error		Limit (nnm)	Dogult
	(Vdc)	Hz	ppm	Limit (ppm)	Result
		QPSK			
	4.35	95	0.113568	±2.5	Pass
25	3.80	80	0.095637		
	3.50	69	0.082487		
		16QAM			
25	4.35	90	0.107591	±2.5	Pass
	3.80	79	0.094441		
	3.50	56	0.066946		

LTE Band 7 part:

Reference Fre	quency: LTE Band 7	(10MHz) Middle	channel=21100	Frequency=2535	.00MHz
Temperature (°C)	Power supplied	Frequency error		Limit (nnm)	Result
	(Vdc)	Hz	ppm	Limit (ppm)	Result
		QPSK			
	4.35	91	0.035897	within authorized band	Pass
25	3.80	72	0.028402		
	3.50	53	0.020907		
		16QAM			
25	4.35	92	0.036292	within authorized band	Pass
	3.80	86	0.033925		
	3.50	68	0.026824		